

VDC	650 V
I _F	100 A
T _{j,max}	175 °C

650V SiC Power Module Dual Diode Pack

Features

- SiC Schottky Diode
 - Zero reverse recovery
 - Zero forward recovery
 - Temperature independent switching behavior
 - Positive temperature coefficient on V_F
- Low stray inductance
- High junction temperature operation
- All parts tested to greater than 715V

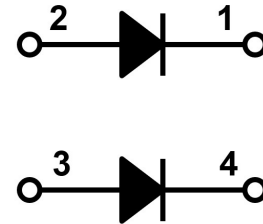
Benefits

- Outstanding performance at high frequency operation
- Low loss and low EMI noise
- Very rugged and easy mounting
- Internally isolated package (AIN)
- Low junction to case thermal resistance
- Easy paralleling due to positive T_C of V_F
- RoHS compliant

Applications

- Switched-mode power supply
- Induction heater
- Welding equipment
- Charging station

Package



Parallel

Part #	Package	Marking
GHXS100B065S-D3	SOT-227	GHXS100B065S-D3



Maximum Ratings, at T_j=25 °C, unless otherwise specified (per leg)

Characteristics	Symbol	Conditions	Values	Unit
Continuous forward current	I _F	T _C =25 °C, T _J =175 °C	193	A
		T _C =122 °C, T _J =175 °C	100	
		T _C =150 °C, T _J =175 °C	59	
Surge non-repetitive forward current sine halfwave	I _{FSM}	T _C =25 °C, t _p =8.3 ms	580	A
		T _C =110 °C, t _p =8.3 ms	540	
Non-repetitive peak forward current	I _{F,max}	T _C =25 °C, t _p =10 μs	2000**	A
i ² t value	∫i ² dt	T _C =25 °C, t _p =8.3 ms	1396	A ² s
		T _C =110 °C, t _p =8.3 ms	1210	
Repetitive peak reverse voltage	V _{RRM}	T _J =25 °C	650	V
Diode dv/dt ruggedness	dv/dt	Turn-on slew rate, repetitive	200	V/ns
Power dissipation	P _{tot} *	T _C =25 °C	480	W
Operating junction temperature	T _J		-55... 175	°C
Storage temperature	T _{storage}		-55... 150	°C

Notes: *Typical R_{thjC} used
**Limited by testing equipment

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Electrical Characteristics, at $T_j=25\text{ }^\circ\text{C}$, unless otherwise specified (per leg)

Characteristics	Symbol	Conditions	Values			Unit
			min.	typ.	max.	
DC blocking voltage	V_{DC}	$I_R=250\mu\text{A}$, $T_j=25\text{ }^\circ\text{C}$	650	-	-	V
Breakdown voltage	V_{BR}	$I_R=3.3\text{mA}$, $T_j=25\text{ }^\circ\text{C}$	715	-	-	V
Diode forward voltage	V_F	$I_F=100\text{A}$, $T_j=25\text{ }^\circ\text{C}$	-	1.45	1.65	V
		$I_F=100\text{A}$, $T_j=125\text{ }^\circ\text{C}$	-	1.61	-	
		$I_F=100\text{A}$, $T_j=175\text{ }^\circ\text{C}$	-	1.77	2.10	
Reverse current	I_R	$V_R=650\text{V}$, $T_j=25\text{ }^\circ\text{C}$	-	11	250	μA
		$V_R=715\text{V}$, $T_j=25\text{ }^\circ\text{C}$	-	45	-	
		$V_R=650\text{V}$, $T_j=125\text{ }^\circ\text{C}$	-	82	-	
		$V_R=650\text{V}$, $T_j=175\text{ }^\circ\text{C}$	-	294	1000	
Total capacitive charge	Q_C	$V_R=400\text{V}$, $T_j=25\text{ }^\circ\text{C}$	-	241	-	nC
Total capacitance	C	$V_R=1\text{V}$, $f=1\text{ MHz}$	-	3891	-	pF
		$V_R=200\text{V}$, $f=1\text{ MHz}$	-	456	-	
		$V_R=400\text{V}$, $f=1\text{ MHz}$	-	377	-	

Thermal and Package Characteristics, at $T_j=25\text{ }^\circ\text{C}$, unless otherwise specified

Characteristics	Symbol	Conditions	Values			Unit
			min.	typ.	max.	
Thermal resistance, junction-case	R_{thJC}	Per leg	-	0.31	0.43	$^\circ\text{C/W}$
Mounting torque	M_d	M4-0.7 screws	1.1	-	1.5	N-m
Terminal connection torque	M_{dt}	M4-0.7 screws	-	1.1	1.3	N-m
Package weight	W_t		-	32	-	g
Isolation voltage	V_{ISOL}	$I_{ISOL} < 1\text{mA}$, 50/60 Hz, 1 min	2500	-	-	V

Typical Performance Per Leg

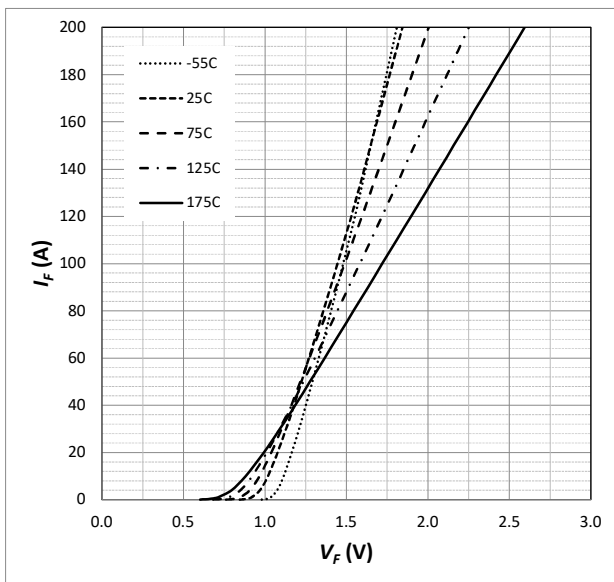


Fig. 1 Forward Characteristics (parameterized on T_j)

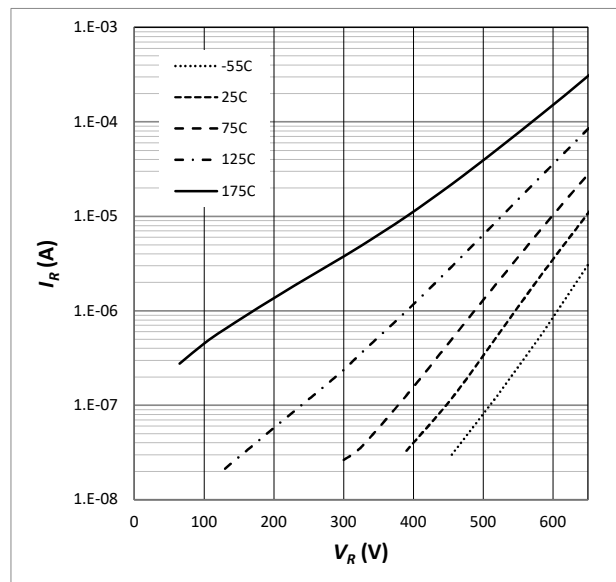


Fig. 2 Reverse Characteristics (parameterized on T_j)

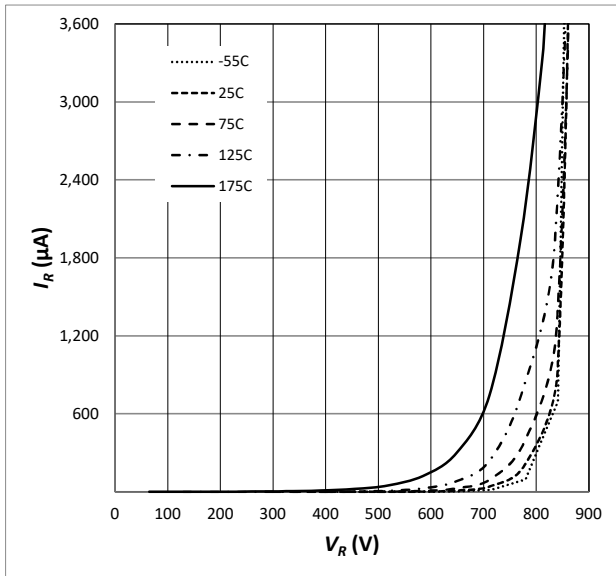


Fig. 3 Reverse Characteristics (parameterized on T_j)

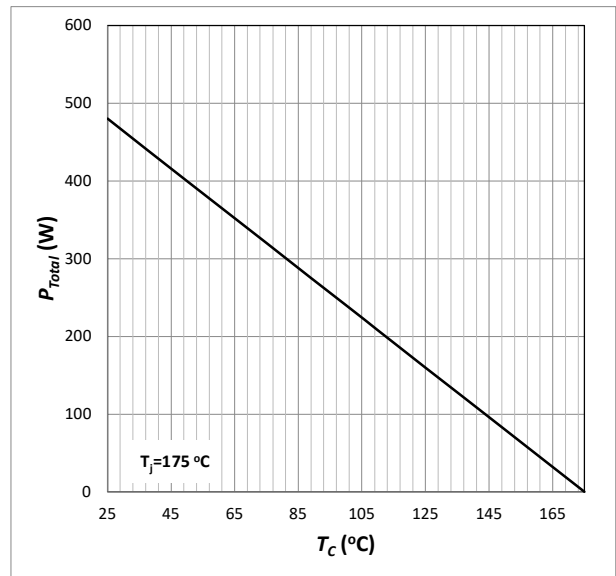


Fig. 4 Power Derating

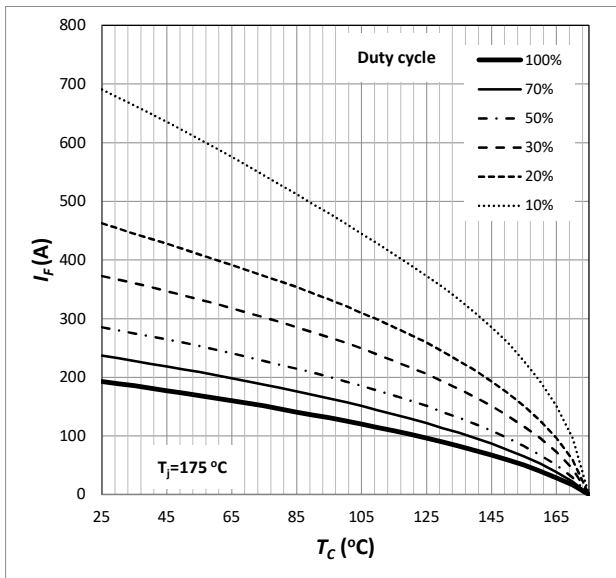


Fig. 5 Current Derating

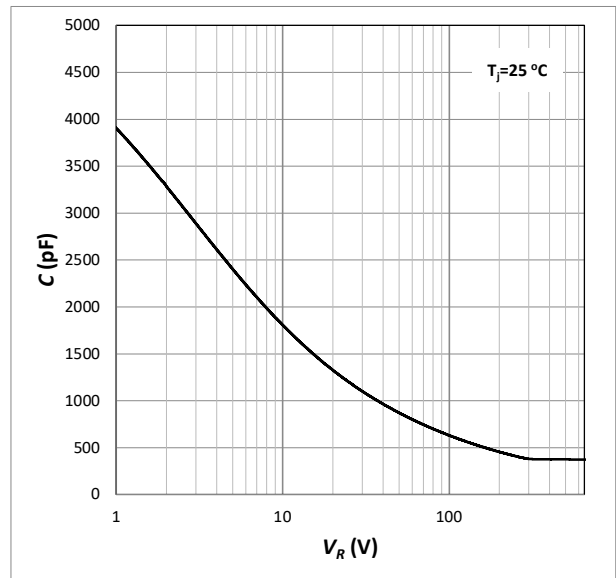


Fig. 6 Capacitance

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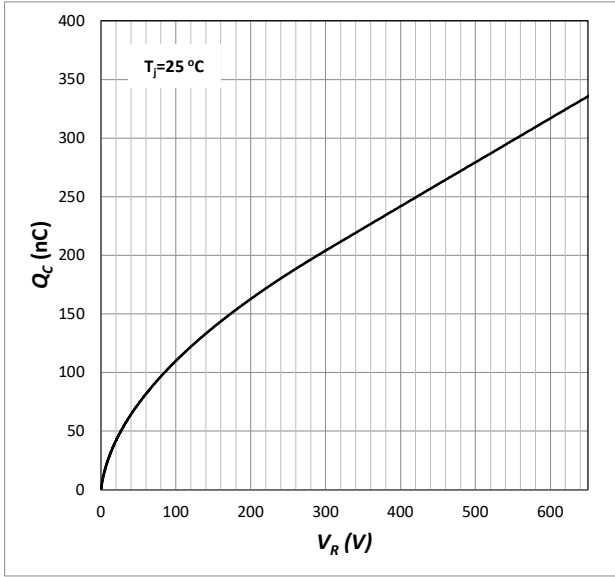


Fig. 7 Capacitive Charge

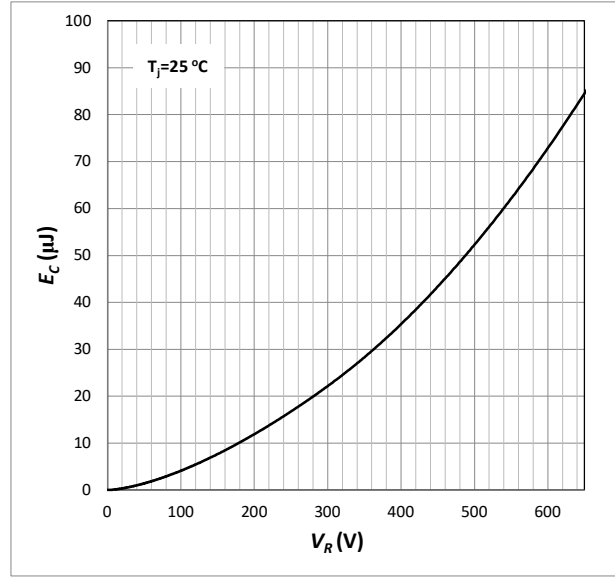


Fig. 8 Typical Capacitance Stored Energy

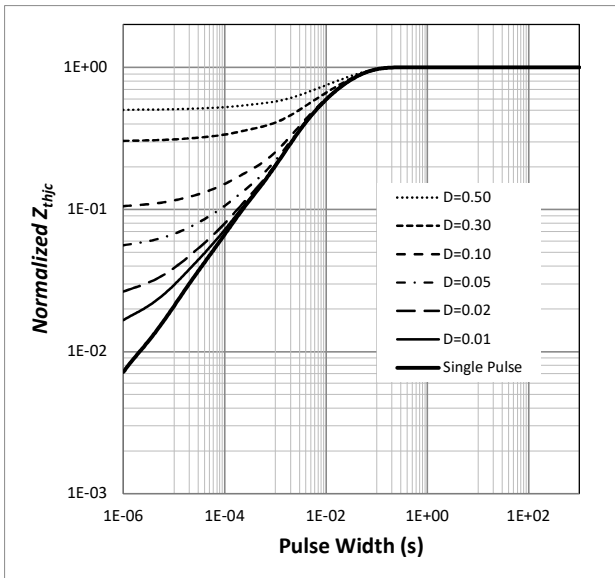
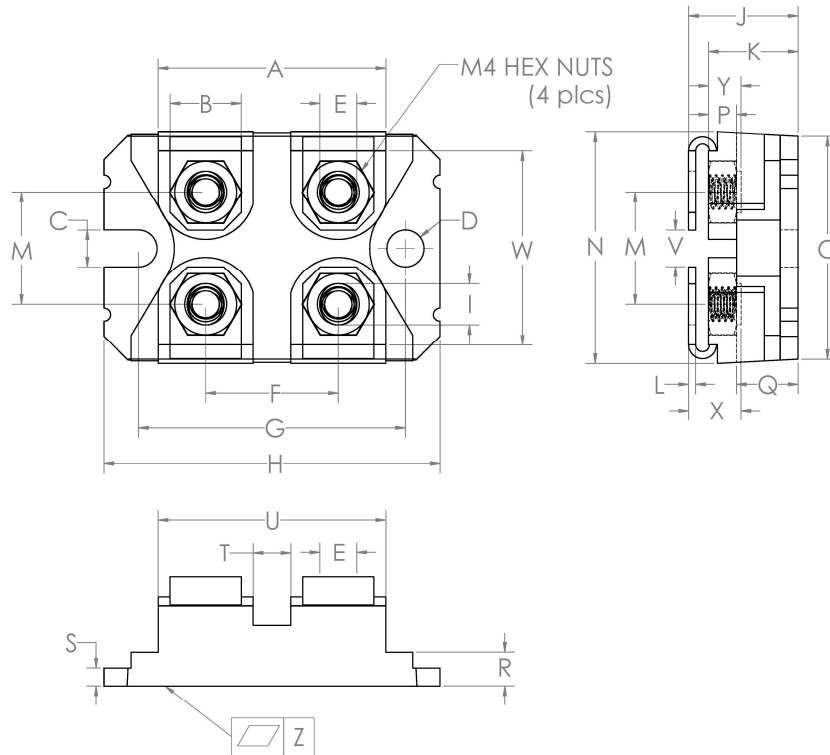


Fig. 9 Transient Thermal Impedance

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Package Dimensions SOT-227



Sym	Millimeters		Inches	
	Min	Max	Min	Max
A	31.67	31.90	1.247	1.256
B	7.95	8.18	0.313	0.322
C	4.14	4.24	0.163	0.167
D	4.14	4.24	0.163	0.167
E	4.14	4.24	0.163	0.167
F	14.94	15.09	0.588	0.594
G	30.15	30.25	1.187	1.191
H	38.00	38.10	1.496	1.500
I	4.75	4.83	0.187	0.190
J	11.68	12.19	0.460	0.480
K	9.45	9.60	0.372	0.378
L	0.76	0.84	0.030	0.033
M	12.62	12.88	0.497	0.507
N	25.15	25.30	0.990	0.996
O	24.79	25.04	0.976	0.986
P	3.02	3.15	0.119	0.124
Q	6.71	6.96	0.264	0.274
R	4.17	4.42	0.164	0.174
S	2.08	2.13	0.082	0.084
T	3.28	3.63	0.129	0.143
U	26.75	26.90	1.053	1.059
V	3.86	4.24	0.152	0.167
W	20.55	26.90	0.809	0.814
X	5.45	5.85	0.215	0.230
Y	3.15	3.66	0.124	0.144
Z	0.00	0.13	0.000	0.005

650V SiC Power Module

GHXS100B065S-D3

Revision History

Date	Revision	Notes
9/16/2020	1.0	Initial release

Notes

RoHS Compliance

The levels of RoHS restricted materials in this product are below the maximum concentration values (also referred to as the threshold limits) permitted for such substances, or are used in an exempted application, in accordance with EU Directive 2011/65/EC (RoHS2), as implemented March, 2013. RoHS Declarations for this product can be obtained from the Product Documentation sections of www.SemiQ.com.

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